TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

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UHF~C BAND LOW NOISE AMPLIFIER APPLICATIONS

• High Gain : $|S_{21e}|^2 = 12dB$ (Typ.)

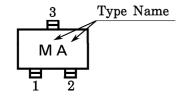
• Low Noise Figure : NF=2.3dB (Typ.), f=1GHz

• High f_T : $f_T=6.5GHz$

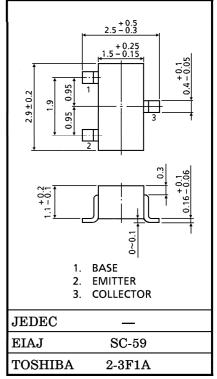
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	20	V
Collector-Emitter Voltage	v_{CEO}	7	V
Emitter-Base Voltage	$ m V_{EBO}$	3	V
Collector Current	$I_{\mathbf{C}}$	30	mA
Emitter Current	$\mathbf{I_E}$	10	mA
Collector Power Dissipation	PC	150	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C

Marking



Unit in mm



Weight: 0.012g

MICROWAVE CHARACTERISTICS (Ta = 25°C)

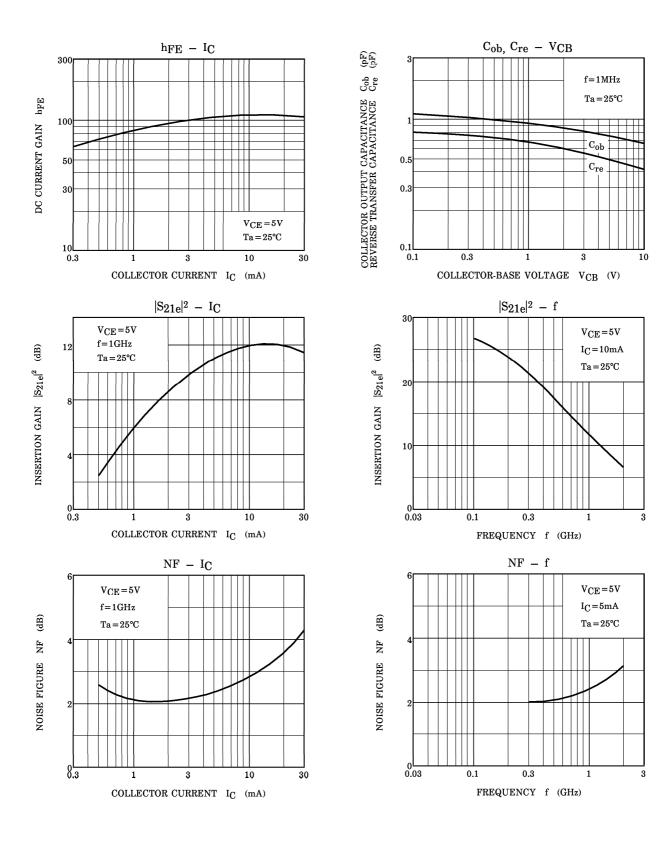
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Transition Frequency	${ m f_T}$	$V_{\text{CE}} = 5V, I_{\text{C}} = 10\text{mA}$	_	6.5	_	GHz
Insertion Gain	$ S_{21e} ^2$	$V_{CE}=5V$, $I_{C}=10$ mA, $f=1$ GHz	_	12	_	dB
Noise Figure	NF	$V_{CE}=5V$, $I_{C}=5mA$, $f=1GHz$	_	2.3	_	dB

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{ m CBO}$	$V_{CB} = 10V, I_{E} = 0$	_	_	1.0	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB} = 1.0V, I_{C} = 0$	_	_	1.0	μ A
Collecter-Emitter Breakdown	V _(BR) CEO	IG = 0.5m A In = 0	7	_		V
Voltage		1C=0.5mA, 1B=0				
DC Current Gain	${ m h_{FE}}$	$V_{\rm CE}$ =5V, $I_{\rm C}$ =10mA	30	120	_	_
Collector-Emitter Saturation	Varia	I_{C} =10mA, I_{B} =1mA		0.1		
Voltage	VCE (sat)			0.1	_	V
Base-Emitter Saturation Voltage	V _{BE (sat)}		_	0.87	_	
Collecter Output Capacitance	C_{ob}	$V_{CB} = 5V, I_{E} = 0,$	_	0.7	0.9	IP
Reverse Transfer Capacitance	$\mathrm{c_{re}}$	f=1MHz (Note)	_	0.5	_	pF
Input Capacitance	$\mathrm{c_{ib}}$	$V_{EB} = 0$, $I_{C} = 0$, $f = 1MHz$	_	0.8	_	рF

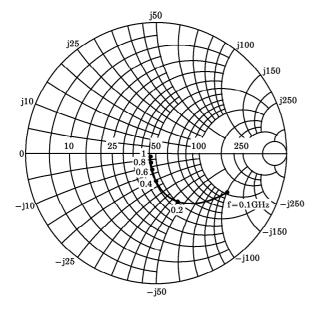
(Note) Cre is measured by 3-terminal method with Capacitance Bridge.

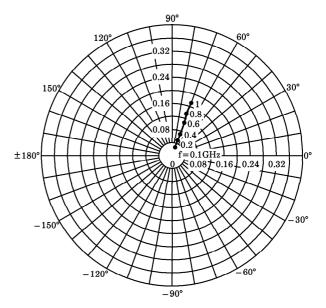


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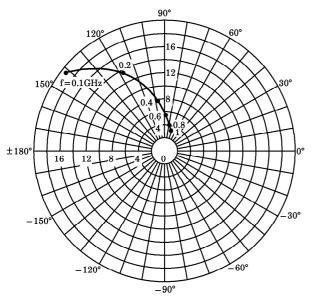
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 10 mA \\ Ta = 25 ^{\circ}C \\ (UNIT: \Omega) \end{array}$

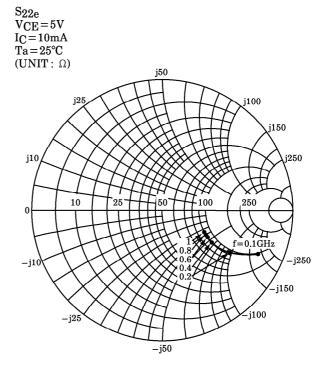






 $\begin{array}{c} \mathrm{S}_{21e} \\ \mathrm{V}_{\mathrm{CE}} \! = \! 5\mathrm{V} \\ \mathrm{I}_{\mathrm{C}} \! = \! 10\mathrm{mA} \\ \mathrm{Ta} \! = \! 25^{\circ}\mathrm{C} \end{array}$





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